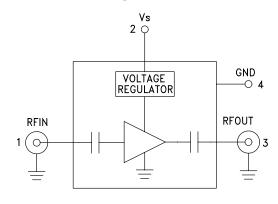


Typical Applications

The HMC-C002 Wideband LNA is ideal for:

- Telecom Infrastructure
- Microwave Radio & VSAT
- Military & Space
- Test Instrumentation
- Fiber Optics

Functional Diagram



Features

Noise Figure: 2 dB @ 8 GHz Flat Gain: 13 dB \pm 0.5 dB

P1dB Output Power: +18 dBm @ 8 GHz

50 Ohm Matched Input/Output

Regulated Supply and Bias Sequencing

Hermetically Sealed Module

Field Replaceable SMA connectors

-55 °C to +85 °C Operating Temperature

General Description

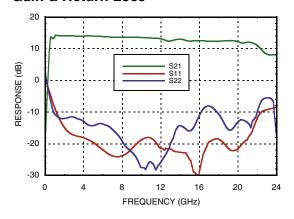
The HMC-C002 is a GaAs MMIC pHEMT Low Noise Distributed Amplifier in a miniature, hermetic module with replaceable SMA connectors which operates between 2 and 20 GHz. The self-biased amplifier provides 13 dB of gain, 2 to 3 dB noise figure and up to +18 dBm of output power at 1 dB gain compression while requiring a single +12V supply. Gain flatness is excellent from 2 - 18 GHz making the HMC-C002 ideal for EW, ECM RADAR and test equipment applications. The wideband amplifier I/Os are internally matched to 50 Ohms and are internally DC blocked.

Electrical Specifications, $T_{\Delta} = +25^{\circ}$ C, Vs = +11.6V to +12.4V

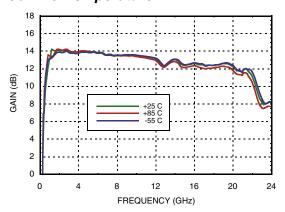
| Parameter | Min. | Тур. | Max. | Min. | Тур. | Max. | Min. | Тур. | Max. | Units |
|--|-----------|-------|------------|------|-------|-------------|------|-------|-------|--------|
| Frequency Range | 2.0 - 6.0 | | 6.0 - 12.0 | | | 12.0 - 20.0 | | | GHz | |
| Gain | 12 | 14 | | 11 | 13 | | 10 | 12 | | dB |
| Gain Flatness | | ±.025 | | | ±0.5 | | | ±0.5 | | dB |
| Gain Variation Over Temperature | | 0.008 | 0.015 | | 0.008 | 0.015 | | 0.008 | 0.015 | dB/ °C |
| Noise Figure | | 2.5 | 4.5 | | 2.0 | 3.0 | | 3.0 | 5.0 | dB |
| Input Return Loss | | 17 | | | 18 | | | 18 | | dB |
| Output Return Loss | | 12 | | | 15 | | | 8 | | dB |
| Output Power for 1 dB Compression (P1dB) | 15 | 18 | | 13 | 16 | | 9 | 12 | | dBm |
| Saturated Output Power (Psat) | | 21.5 | | | 21 | | | 19 | | dBm |
| Output Third Order Intercept (IP3) | | 26.5 | | | 26 | | | 23 | | dBm |
| Spurious Response | | -50 | | | -60 | | | -60 | | dBc |
| Supply Current | | 93 | | | 93 | | | 93 | | mA |



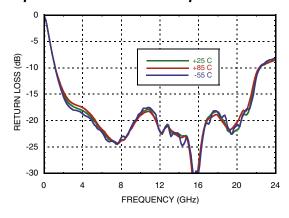
Gain & Return Loss



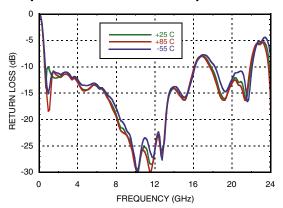
Gain vs. Temperature



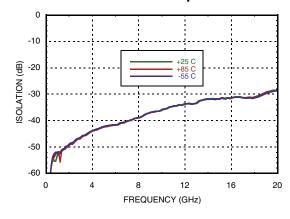
Input Return Loss vs. Temperature



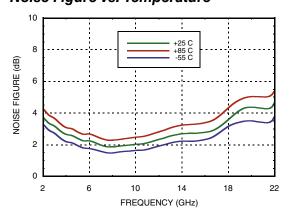
Output Return Loss vs. Temperature



Reverse Isolation vs. Temperature

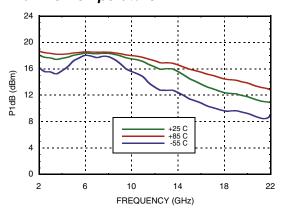


Noise Figure vs. Temperature

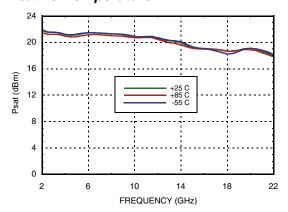




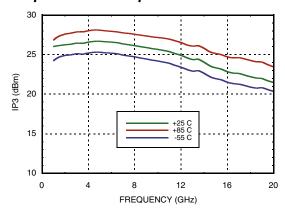
P1dB vs. Temperature



Psat vs. Temperature



Output IP3 vs. Temperature



Absolute Maximum Ratings

| Bias Supply Voltage (Vs) | +11 Vdc to +13 Vdc |
|--------------------------|--------------------|
| RF Input Power (RFIN) | +18 dBm |
| Storage Temperature | -65 to +150 °C |
| Operating Temperature | -55 to +85 °C |

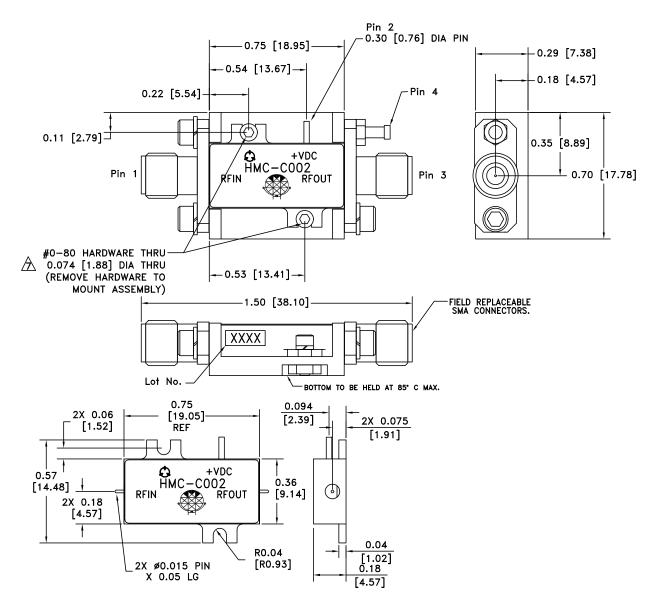


Pin Descriptions

| Pin Number | Function | Description | Interface Schematic | |
|------------|----------------------|--|----------------------|--|
| 1 | RFIN & RF Ground | RF input connector, SMA female, field replaceable. This pin is AC coupled and matched to 50 Ohms. | RFINO— — | |
| 2 | Vs | Power supply voltage for the amplifier. | VS VOLTAGE REGULATOR | |
| 3 | RFOUT & RF Ground | RF output connector, SMA female. This pin is AC coupled and matched to 50 Ohms. | → → RFOUT | |
| 4 | GND | Power supply ground. | GND = | |



Outline Drawing



Package Information

| Package Type | C-2 |
|--------------------|-------------------------|
| Package Weight [1] | 11.2 gms ^[2] |
| Spacer Weight | N/A |

- [1] Includes the connectors
- [2] ±1 gms Tolerance

NOTES

- 1. PACKAGE, LEADS, COVER MATERIAL: KOVAR™
- 2. BRACKET MATERIAL: ALUMINUM
- 3. PLATING: ELECTROLYTIC GOLD 50 MICROINCHES MIN., OVER ELECTROLYTIC NICKEL 75 MICROINCHES MIN.
- 4. ALL DIMENSIONS ARE IN INCHES [MILLIMETERS].
- 5. TOLERANCES $\pm .005$ [0.13] UNLESS OTHERWISE SPECIFIED.
- 6. FIELD REPLACEABLE SMA CONNECTORS. TENSOLITE 5602 - 5CCSF OR EQUIVALENT.
- ↑TO MOUNT MODULE TO SYSTEM PLATFORM REPLACE 0 -80 HARDWARE WITH DESIRED MOUNTING SCREWS.